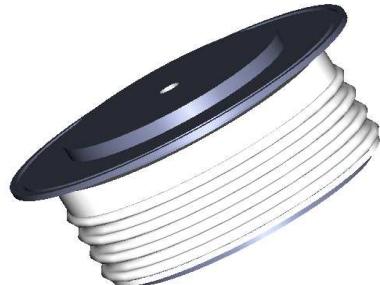


GPDN1230

RECTIFIER DIODE



VOLTAGE UP TO	1000 V
AVERAGE CURRENT	2300 A
SURGE CURRENT	28 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V _{RRM}	Repetitive peak reverse voltage	1000 V
V _{RSM}	Non-repetitive peak reverse voltage	1100 V
I _{RRM}	Repetitive peak reverse current, max.	50 mA

FORWARD CHARACTERISTICS

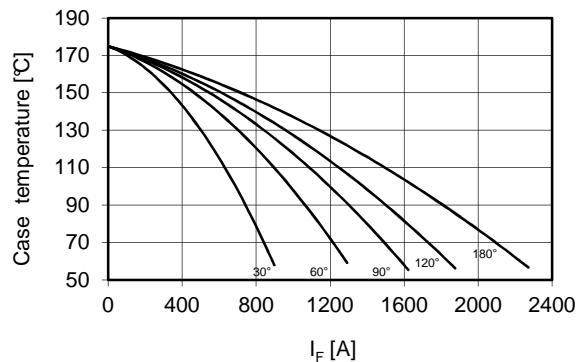
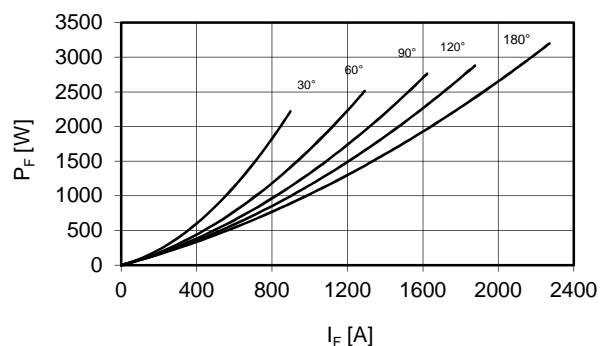
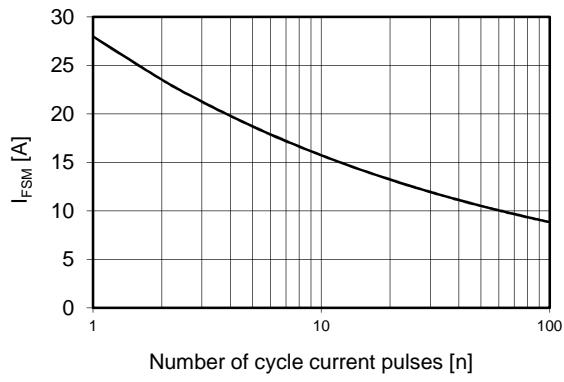
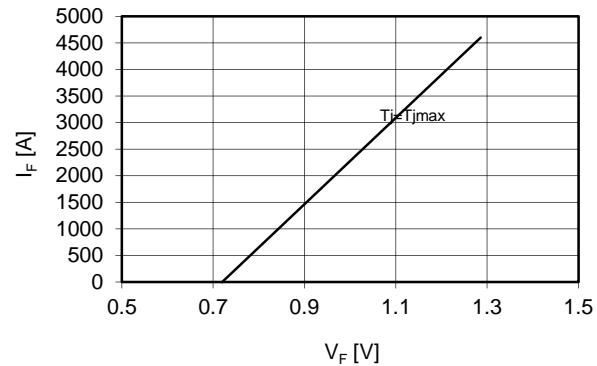
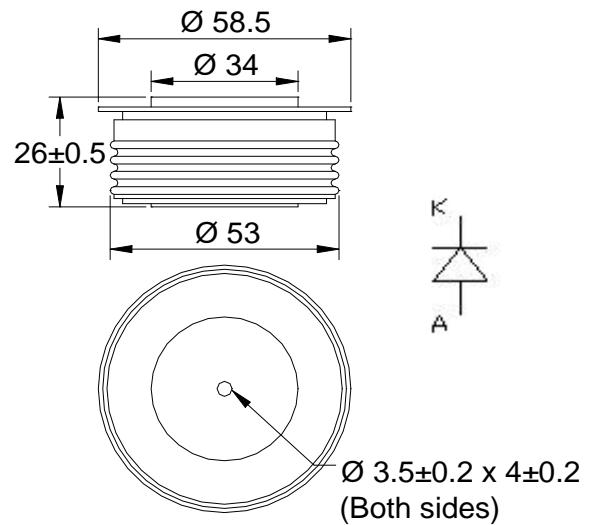
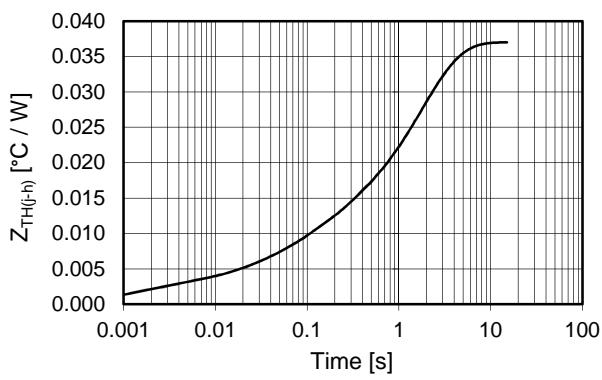
I _{F(AV)}	Average forward current	Sine wave, 180° conduction, T _h = 55°C	2300 A
I _{F(RMS)}	R.M.S. forward current	Sine wave, 180° conduction, Th = 55°C	3613 A
I _{FSM}	Surge forward current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	28 kA
I ² t	I ² t for fusing coordination		3920 kA ² s
V _{F(TO)}	Threshold voltage	T _j = T _{jmax}	0.72 V
r _F	Forward slope resistance	T _j = T _{jmax}	0.123 mΩ
V _{FM}	Peak forward voltage, max	Forward current I _F = 4000 A, T _j = T _{jmax}	1.21 V

SWITCHING CHARACTERISTICS

Q _{rr}	Rverse recovery charge, typ	T _j = T _{jmax} , I _F = 1000 A, dI/dt = -5 A/μs	μC
I _{rr}	Reverse recovery current		A

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-h)}	Thermal resistance (junction to heatsink)	Double side cooled	0.037 °C/W
T _{jmax}	Max operating junction temperature		175 °C
T _{stg}	Storage temperature		-40 / 175 °C
F	Clamping force ± 10%		12 kN
	Mass		300 g

Current rating - sine wave

Power loss - sine wave

**Maximum surge current
d.s. cooled**

Forward voltage drop

Thermal Impedance ($j-h$)


In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.